

## Oral Presentations NGS15

*Plenary talks 40 minutes, Invited talks 30 minutes, Contributed talks 20 minutes, including 5 minutes of discussions*

	<b>Monday August 1</b>	<b>Location</b>
1:30-3:30 PM	Registration	Lobby of Hancock Hall
3:30-4:30 PM	Welcoming Reception	Hancock Hall, Room 100
4:30-4:45 PM	Welcoming Comments by Giti Khodaparast and the Vice President for Research	Hancock Hall, Room 100
4:45-5:25 PM	<b>Plenary Talk:</b> History of narrow gap systems	B. McCombe, SUNY Buffalo, USA
5:25- 6:05 PM	<b>Plenary Talk:</b> Dirac fermions in HgTe quantum wells	L. Molenkamp, Universität Würzburg, Germany
6:05-6:45 PM	<b>Plenary Talk:</b> Topological Surface States, Topological Insulators and Superconductors	Z. Hasan, Princeton University, USA
	<b>Tuesday August 2, Morning Sessions</b>	<i>Hancock Hall, Room 100</i>
<b>Session 1</b>	<b>Topological Insulators, Session Chair: Zahid Hasan</b>	
8:20-8:50 AM	<b>Invited Talk:</b> Robustness of topologically protected surface states in layering of Bi <sub>2</sub> Te <sub>3</sub> thin films	K. Park, Virginia Tech, USA
8:50-9:10 AM	Spin phenomena and pseudospin quantum Hall ferromagnetism in the HgTe quantum well	M. V. Yakunin, Inst. Met., Ekaterinburg, Russia
9:10-9:30 AM	THz response and colossal Kerr effect in the topological insulator Bi <sub>2</sub> Se <sub>3</sub>	R. V. Aguilar, The Johns Hopkins Univ., USA
9:30-9:50 AM	Effect of electron-electron interaction on surface transport in three dimensional topological insulators	H. K. Pal, University of Florida, USA
9:50-10:20 AM	Coffee Break	Lobby of Hancock Hall
<b>Session 2</b>	<b>Graphene, Session Chair: Bruce McCombe</b>	
10:20-10:50 AM	<b>Invited Talk:</b> Terahertz dynamics in graphene	V. Ryzhii, University of Aizu, Japan
10:50-11:10 AM	Spatially resolving edge states of chiral graphene nanoribbons	C. Tao, UC Berkeley, USA
11:10-11:30 AM	Terahertz radiation helicity induced electric currents in graphene	P. Olbrich, University of Regensburg, Germany
11:30-11:50 AM	Coherent phonons in carbon nanotubes and graphene	G. Sanders, Univ. of Florida, USA
11:50-12:10 PM	Modeling flat-band nanostructures	V. Scarola, Virginia Tech, USA
12:10-1:45 PM	<b>Lunch Break, Hosted by the Conference</b>	<b>Virginia Tech Inn</b>
	<b>Tuesday August 2, Afternoon Sessions</b>	<i>Hancock Hall, Room 100</i>
<b>Session 3</b>	<b>Transport, Spin dependent Phenomena, Devices 1, Session Chair: Jean Heremans</b>	
1:50-2:20 PM	<b>Invited Talk:</b> Towards room temperature InSb 2DEG nanosensors	A. Gilbertson, Imperial College, UK
2:20-2:40 PM	Electron spin alignment in InSb Type-II quantum dots in an InAs matrix	M. S. Mukhin, Ioffe Institute, Russia
2:40-3:00 PM	Spin dependent transverse electron focusing of spin polarized photocurrents in InSb/InAlSb QW devices	J. Li, University of Surrey, UK
3:00-3:20 PM	Single electron transport through site-controlled InAs quantum dots probed by nanogap electrodes	K. M. Cha, University of Tokyo, Japan
3:20-3:40 PM	Coffee Break	Lobby of Hancock Hall
<b>Session 4</b>	<b>Transport, Spin dependent Phenomena, Devices 2, Session Chair: Louis Guido</b>	
3:40-4:00 PM	Determination of spin-orbit coefficients in InGaAs/InAlAs quantum wells	T. Koga, Hokkaido University, Japan
4:00-4:20 PM	Large spin and non-parabolicity effects in InGaAs/GaAsSb resonant tunneling diodes	J. Sousa, Inst. Festkoerperelektronik, Austria
4:20-4:40 PM	Enhanced hole mobility and density in GaSb quantum wells for p-channel FETs	B. R. Bennett, Naval Research Laboratory, USA
4:40-5:00 PM	Nonlocal transport in PbTe/PbEuTe microstructures	K. A. Kolwas, Instytut Fizyki PAN, Poland
5:00-7:00 PM	<b>Posters and Refreshments</b>	<b>Lobby of Hancock Hall</b>

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<b>Wednesday August 3, Morning Session</b>		<i>Hancock Hall, Room 100</i>
<b>Session 5</b>	<b>QCL and Detectors 1, Session Chair: Ben Murdin</b>	
8:20-8:50 AM	<b>Invited Talk:</b> Quantum cascade detectors and THz lasers	F. Julien, Univ. Paris-Sud, France
8:50-9:10 AM	A new generation of interband cascade lasers	J. Meyer, Naval Research Laboratory, USA
9:10-9:30 AM	135 K operation of InGaAs/GaAsSb Terahertz quantum cascade lasers	C. Deutsch, Vienna Univ. of Tech., Austria
9:30-9:50 AM	Two dimensional integration of ring cavity surface emitting quantum cascade lasers	C. Schwarzer, Vienna Univ. of Tech., Austria
9:50-10:10 AM	Coffee Break	Lobby of Hancock Hall
<b>Session 6</b>	<b>QCL and Detectors 2, Session Chair: Jerry Meyer</b>	
10:10-10:40 AM	<b>Invited Talk:</b> Lead salt microdisk lasers	G. Springholz, Univ. of Linz, Austria
10:40-11:00 AM	Quantum dot IR photodetectors and solar cells enhanced by built-in-charge	V. Mitin, SUNY Buffalo, USA
11:00-11:20 AM	High operability 1024×1024 long wavelength infrared focal plane array based on type-II InAs/GaSb superlattices	A. Haddadi, Northwestern University, USA
11:20-11:40 AM	New approaches to bulk, direct bandgap III-V materials for long-wavelength infrared detectors	W. Sareny, US Army Research Laboratory, USA
<b>Bus Tour starts at 12:00 PM, Lunch Boxes Provided</b>		
<b>Excursion/Banquet</b>		
<b>Thursday August 4, Morning Session</b>		<i>Hancock Hall, Room 100</i>
<b>Session 7</b>	<b>Mercury Cadmium Telluride, Session Chair: Hiro Munekata</b>	
8:20- 8:50 AM	<b>Invited Talk:</b> Negative-band-gap quantum dots	N. Malkova, KLA-Tencor Company, USA
8:50 -9:10 AM	Correlation between band structure, Hall, Seebeck and Shubnikov-De Haas effects in a two dimensional far infrared detector n-type HgTe/CdTe superlattice	A. Nafidi, Ibn Zohr University, Morocco
9:10-9:20 AM	Restructuring of the phonon spectra of the MCT and MZT alloy at the Dirac point-singularity	E. M. Sheregii, University of Rzeszow, Poland
9:20-9:40 AM	Photoluminescence, photoreflexion and optical absorption of HgCdSe	D. Miranda, Univ. Ind. de Santander, Colombia
9:40-10:00 AM	Magneto-optical response of HgMnTe alloys quantum wells and superlattices	D. Talwar, Indiana Univ. of Pennsylvania, USA
10:00-10:30 AM	Coffee Break	Lobby of Hancock Hall
<b>Session 8</b>	<b>Terahertz and Coherent Phenomena, Session Chair: Chris Stanton</b>	
10:30-11:00 AM	<b>Invited Talk:</b> THz coherent control in Si	B. Murdin, Univ. of Surrey, UK
11:00-11:20 AM	Time resolved THz magneto-optical polarization modulation spectroscopy	A. Stier, SUNY Buffalo, USA
11:20-11:40 AM	Detection of a coherent longitudinal optical phonon in a GaAs buffer layer optically covered with a GaSb top	H. Takeuchi, Univ. of Shiga Prefecture, Japan
11:40 -12:00 PM	Synchronized mid-infrared beam characterization of narrow gap semiconductors	L. Olafsen, Baylor University, USA
12:00-1:45 PM	<b>Lunch Break, Hosted by the Conference</b>	<b>Virginia Tech Inn</b>

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<b>Thursday August 4, Afternoon Session</b>		<i>Hancock Hall, Room 100</i>
<b>Session 9</b>	<b>Narrow Gap and Magnetic Semiconductors 1, Session Chair: Mike Santos</b>	
1:50-2:10 PM	<b>Invited Talk:</b> Terahertz studies of collective excitations in InSb magneto-plasmas	A. Belyanin, Texas A&M, USA
2:10-2:30 PM	Magnetogyrotropic photogalvanic effects in InSb-based low-dimensional structures	S. Stachel, University of Regensburg, Germany
2:30-2:50 PM	Rashba and Dresselhaus spin-orbit interaction strength in III-V 2DEG system	E. A. de Andrada e Silva, Inst. Nac. de Pesquisas Espaciais, Brazil
2:50-3:10 PM	Probing spin-relaxation anisotropy in 1D InSb wires by weak anti-localization	P. Jayathilaka, University of Oklahoma, USA
3:10-3:40 PM	<b>Coffee Break</b>	<b>Lobby of Hancock Hall</b>
<b>Session 10</b>	<b>Narrow Gap and Magnetic Semiconductors 2, Session Chair: Takaaki Koga</b>	
3:40-4:00 PM	Evaluation of spin polarization in p-InMnAs using Andreev reflection spectroscopy including inverse proximity effect	H. Munekata, Tokyo Inst. of Technology, Japan
4:00-4:20 PM	(In,Mn)Sb studies by Cross-Sectional STM	S. J. C. Mauger, Eindhoven I.T., Netherlands
4:20-4:40 PM	Electron g-factor of Mn ions in GeMnTe	W. Knoff, Polish Academy of Sciences, Poland
4:40-5:00 PM	Giant Zeeman effect for two-dimensional electrons in InAs quantum wells with manganese doped ZnTe barrier	Ya. Terentev, Ioffe Institute, Russia
5:00-7:00 PM	<b>Posters and Refreshments</b>	<b>Lobby of Hancock Hall</b>
<b>Friday August 5, Morning Session</b>		
<b>Session 11</b>	<b>New Substrates, Session Chair: Natalia Malkova</b>	
8:20-8:50 AM	<b>Invited Talk:</b> PbSe nanocrystals, nanorods, and nanowires	J. Tischler, Naval Research Laboratory, USA
8:50-9:10 AM	Substrate dependence of PbTe nanowire growth	P. Dziawa, Polish Academy of Sciences, Poland
9:10-9:30 AM	Photoconductivity of PbTe(In) films with variable microstructures	V. I. Chernichkin, Moscow State Univ., Russia
9:30-9:50 AM	Topological insulators Bi <sub>2</sub> Te <sub>3</sub> and Bi <sub>2</sub> Se <sub>3</sub> grown by MBE on (100) GaAs substrate	X. Liu, University of Notre Dame, USA
9:50-10:10 AM	PbSe quantum well VECSEL on Si	M. Fill, ETH Zurich, Switzerland
10:10-10:40 AM	<b>Coffee Break</b>	<b>Lobby of Hancock Hall</b>
<b>Session 12</b>	<b>Optical and Magneto-Optical Phenomena, Session Chair: E. A. de Andrada e Silva</b>	
10:40-11:00 AM	Magneto-optical properties of narrow-gap semiconductor heterostructures	X. Pan, University of Florida, USA
11:00-11:20 AM	Recombination and optical properties of unrelaxed InAsSb grown by MBE on GaSb and InSb substrates	D. Donetsky, Stony Brook University, USA
11:20-11:40 AM	Mid-Infrared Continuously Tunable Single Mode VECSEL	A. Khiar, ETH Zurich, Switzerland
11:40-12:00 PM	Optical properties of strain-balanced InAs/InAs(1-x)Sb(x) type-II superlattices	E. H. Steenberg, Arizona State Univ., USA
12:20-12:30 PM	<b>Conference Announcements</b>	